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Importance of two current model in understanding the electronic transport behavior of inverse Heusler alloy: Fe_2CoSi

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Abstract. Here we explore the applicability of the two current model in understanding the transport behavior of Fe_2CoSi compound by using the first principles calculations in combination with the Boltzmann transport theory. The spin-unpolarized calculation shows large density of states (DOS) at Fermi level (E_F) and is unable to provide the correct temperature dependence of transport coefficients. The spin-polarised calculation shows reduced DOS at the E_F in the spin-up channel, whereas spin-dn channel have almost zero DOS at the E_F. The absolute value of Seebeck coefficient in the spin-up channel shows linear increment with the temperature and in the spin-dn channel it varies non-linearly. The electrical conductivity also shows non-linear temperature dependence in both the spin channels whereas, the electronic thermal conductivity shows linear temperature dependence. The values of transport coefficients and their temperature dependence obtained by using the two current model are found to be in fairly good agreement with the experimental data. Present work clearly suggests the importance of two current model in understanding the transport properties of the compound.

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1. Introduction

In the ferromagnetic metals one can distinguish the electrons, according to the parallel or antiparallel direction of their magnetic moment to the total magnetization. The charge carriers parallel to the total magnetization are referred as spin-up electrons and antiparallel to the total magnetization are referred as spin-dn electrons. In these materials the two bands are not equally filled and hence lead to a non-zero magnetization. Mott described that the spin splitting of the energy bands in the ferromagnetic spin states induces the specific transport behavior[1]. He gave a model for the electrical conduction in ferromagnetic transition metals by considering the two independent parallel currents, carried by spin-up and spin-dn electrons. In the two current model the scattering events with the conservation of spin direction become more probable at low temperature i.e. at temperature lower than the Curie temperature (T_c). Above T_c, the application of the two-current model is limited by spin-mixing effects.

According to this model, in the absence of any spin-flip processes the resistivities from two spin channels are added as that of two parallel resistors. The resulting average isotropic resistivity is given by

$$1/\rho = 1/\rho^{\uparrow} + 1/\rho^{\downarrow} \tag{1}$$

and hence the total conductivity can be expressed as[2]

$$\sigma = \sigma^{\uparrow} + \sigma^{\downarrow} \tag{2}$$

where $\rho^{\uparrow}$ and $\rho^{\downarrow}$ are the resistivities and $\sigma^{\uparrow}$ and $\sigma^{\downarrow}$ are the conductivities of the spin-up and spin-dn channels, respectively.

In the two current model the total Seebeck coefficient (S) can be expressed as the average of Seebeck coefficients from both the channels weighted by the corresponding conductivities[3, 4]

$$S = [\sigma^{\uparrow}S^{\uparrow} + \sigma^{\downarrow}S^{\downarrow}]/[\sigma^{\uparrow} + \sigma^{\downarrow}] \tag{3}$$

where, $S^{\uparrow}$ and $S^{\downarrow}$ are the Seebeck coefficients of the spin-up and spin-dn channels, respectively. The effective electronic thermal conductivity (κ_e) can be expressed as[5]

$$\kappa_e = \kappa_e^{\uparrow} + \kappa_e^{\downarrow} \tag{4}$$

The two current model has successfully been applied to understand the transport properties of ferromagnetic transition metals[2, 6, 7] and even for antiferromagnetic transition-metal oxides[4]. As stated earlier this model is applicable well below the T_c and compounds with higher T_c are important for technological applications. Therefore, in the previous calculations we have applied this model to study Co_2MnGe Heusler alloy having T_c equals to 905 K[8]. But we did not find much importance of the model in the compounds because of the presence of the large band gap ($\sim$ 0.4 ev) in the spin-dn channel. This motivates us to search for the compound with very small spin-dn band gap so that this channel can also participate in the transport behavior of the

compound. We came across the Fe_2CoSi compound which has almost negligible band gap in the spin-dn channel. This compound is having a Curie temperature of 1038 K[9]. Based on first principles calculations, Luo et al. have shown that Fe_2CoSi is typical half-metallic ferromagnets[10]. However, Du et al. have proposed it as a gapless half-metallic ferromagnetic alloy[9]. Half-metallic ferromagnets have attracted scientific and technological interest because of their potential in spintronic applications[11]. In these compounds only one spin channel contributes to the transport properties if the band gap of the another one is large. However, contributions from both the channels are expected when the band gap becomes almost zero. Thus in Fe_2CoSi compound both the spin channels are expected to play an important role in deciding the transport properties of this compound. Ishii et al have reported the temperature dependent data of Seebeck coefficient, electrical conductivity and electronic thermal conductivity of Fe_2CoSi above the room temperature[12] and show significant temperature dependence. In the light of these data it will be interesting to see the applicability of the two current model in this compound.

Here we report the electronic and transport properties of Fe_2CoSi alloy by using the electronic structures calculations and the Boltzmann transport theory. The spin-unpolarized calculation shows ~ 25 states/eV/f.u. (f.u. $\equiv$ formula unit) at the E_F and do not provide the correct temperature dependence of the transport coefficients. The spin-polarized calculation provides ~ 1 states/eV/f.u. DOS at the E_F for the spin-up channel while the spin-dn channel has almost zero DOS. In the spin-up channel the absolute value of S increases linearly with the temperature and in the spin-dn channel it varies non-linearly. In both the channels the electrical conductivity is found to vary non-linearly, whereas the electronic thermal conductivity varies linearly with the temperature. The overall temperature dependence of the transport coefficients is computed by combining the contributions from both the channels under two current model. The transport coefficients data thus obtained agree fairly well with the experimental data.

2. Computational details and Crystal structure

The electronic, magnetic and thermoelectric properties of the compound are studied by using the full potential linearized augmented plane-wave (FP-LAPW) method implemented in WIEN2k code[13] in combination with the BoltzTraP code[14]. The exchange-correlation functional was taken within the generalized gradient approximation (GGA) of Perdew et al.[15]. The muffin-tin radii were fixed to 2.25 Bohr (a_0) for Fe atom, 2.30 a_0 for Co atom and 1.90 a_0 for Si atom. $R_{MT}K_{MAX}$ was set equal to 8, where R_{MT} is the smallest atomic sphere radii and K_{max} is the plane wave cut-off. The self-consistency was achieved by demanding the convergence of the total energy/cell and charge/cell of the system to be less than 10^{-5} Ry and 10^{-3} electronic charge, respectively. The k-integration mesh was set to a size of $(50 \times 50 \times 50)$ during the calculations of electronic and transport properties. The *lpfac* parameter, which represents the number

of k-points per lattice point was kept equal to 5 during the calculations of the transport coefficients. The value of relaxation time (τ) was taken to be $5 \times 10^{-15}s$[16], whenever not mentioned.

Generally, Heusler alloys prefer two kinds of structure. One is Cu_2MnAl-type structure having space group $Fm-3m$ and the other is Hg_2CuTi-type structure having space group $F-43m$. The Heusler alloys which crystallize in Hg_2CuTi-type structure are known as inverse Heusler alloys and Fe_2CoSi belongs to this. These are named so because in these alloys the atomic number of Y atom is more than the X atom of the same period i.e. if $Z(Y) > Z(X)$, opposite to that of traditional Heusler alloys. In this structure the two Fe atoms occupy the $4a(0,0,0)$ and $4c(1/4,1/4,1/4)$ Wyckoff positions, while Co and Si atoms occupy $4b(1/2,1/2,1/2)$ and $4d(3/4,3/4,3/4)$ positions, respectively[17, 18]. In this paper Fe_1 and Fe_2 represent the Fe atoms occupying the $4a$ and $4c$ Wyckoff positions, respectively.

3. Results and discussions

Firstly, we will proceed with the discussion of spin-unpolarized calculation to see how far this calculation is going to help in understanding the transport behavior of the compound. The electronic band structure along the high symmetry direction in the first Brillouin zone (BZ) is shown in the Fig. 1(a). This figure shows that Fe_2CoSi is metallic as two bands are crossing the E_F at 10 different k-points along the W to K direction. Many bands are concentrated around the W point along the X to K direction and the system seems to be unstable. Such systems can minimize their energy by shifting these bands and this can lead to the ferromagnetic (FM) ground state as per Stoner theory[19, 8].

The total density of states (TDOS) and partial density of states (PDOS) plots are presented in Fig. 1. It is clear from Fig. 1(b) that there is very large density of states $\sim$ 25 states/eV/f.u. at the E_F. Since in the present system the E_F is mainly contributed by the d orbitals with negligibly small contribution from the other orbitals, so we have shown the partial density of states (PDOS) of Fe and Co atoms in Fig. 1. The PDOS plot of Fe_1 atom is presented in Fig. 1(c). This plot shows that around E_F the main contribution ($\sim$ 5 states/eV/atom) is from the e_g states with small contribution ($\sim$ 1 states/eV/atom) from the t_{2g} states. The Fe_2 atom shown in Fig. 1(d), provides more contribution than the Fe_1 atom at the E_F. The contributions from the e_g and t_{2g} states are $\sim$ 7 and 4 states/eV/atom, respectively at the E_F. From the PDOS of Co atom (Fig. 1(e)) it is clear that at E_F the large contribution is from e_g states ($\sim$ 6 states/eV/atom) and from the t_{2g} states it is small. The DOS plots of Fe_1 and Co atom show three peak structures because of the presence of four fold symmetry in these atoms, whereas Fe_2 atom show mainly two peak structures as it is eight fold symmetric. From the study of PDOS plots of these atoms it is clear that the transport behavior of the compound is mainly governed by the e_g states and the contribution from the Fe_2 atom is more.

Now we study the temperature dependent transport behavior of the compound

obtained from spin-unpolarized calculations. The variations of S, electrical conductivity (σ/τ) and electronic thermal conductivity (κ_e/τ) (where τ is the relaxation time) with temperature are shown in Fig. 2. The value of S remains negative in the entire temperature range which implies that this compound is n-type. The absolute value of S is found to increase with temperature upto 350 K and after that it decreases with increasing temperature as is clear from Fig. 2(a). The absolute value of S at the room temperature comes out to be $\sim$ 30 μVK^{-1}. The value of σ/τ shown in Fig. 2(b), decreases with temperature and become almost constant at the higher temperature. The room temperature value of σ is found to be $\sim$ 13,000 $\Omega^{-1}cm^{-1}$. Fig. 2(c) shows the almost linear increment in κ_e/τ with increasing temperature. The value of κ_e is $\sim$ 9 $Wm^{-1}K^{-1}$. On comparing the temperature dependent behavior of the transport coefficients with the experimental results[12] one can easily concluded that the spin-unpolarized calculation is unable to explain the temperature dependent behavior of the experimental data.

As the spin-unpolarized transport coefficients do not show agreement with the experimental results, so we have studied the compound using the spin-polarized calculation. The spin-polarized calculation is expected to change the DOS around the E_F by shifting the bands and consequently the transport behavior. The spin-polarized dispersion curves along the high symmetry direction of 1st BZ are presented in the Fig. 3(a and b). The spin-up channel is found to be metallic as 3 highly dispersing bands are crossing the E_F at 6 different k-points along the W to K direction. In the spin-dn channel one can find that the bands are not much dispersing and they slightly cross the E_F at Γ and X-points. Thus this compound show almost half-metallic ferromagnetic behavior. Also the band structure of the spin-dn channel of this inverse Heusler alloy differes from the normal Heusler alloys, where one can see the almost flat conduction band along Γ to X-direction[8, 20, 21, 22, 23, 24, 25]. The density of states plots of Fe_2CoSi are also presented in the Fig. 3. In the TDOS plot shown in Fig. 3(c) there are three peaks in the valence band of the minority and majority spin channels as is observed in case of spin-unpolarized calculation. The TDOS at the E_F of majority spin channel is $\sim$ 1 states/eV/f.u and is nearly 25 times less than the spin-unpolarized calculation. In the spin-dn channel there is negligibly small DOS at the E_F so this channel show almost semiconducting behavior. Similar TDOS plot for this compound is also observed in the earlier theoretical work[9, 10, 18].

To see the contributions from various atomic states around the E_F, we have presented PDOS plots in Fig. 3(d-f). In these plots only d-orbitals are shown for the Fe_1, Fe_2 and Co atoms. The spin-up channel of Fe_1 and Co atoms is contributed by both t_{2g} and e_g states, with the value less than 0.5 states/eV/atom at the E_F. In the spin-dn channel, the E_F is at the edge of the t_{2g} states of Fe_1 and Co atoms and shows the almost semiconducting behavior. The PDOS plot of Fe_2 atom shows only two peak structure. In the majority spin channel there are two peaks below the E_F and in the minority spin channel one peak is below and other is above the E_F due to the exchange splitting. It is clear from these plots that, mainly the t_{2g} states of Fe_1 and Co atoms are

contributing to the DOS around the E_F in the minority spin channel. Thus in Fe_2CoSi, the contribution in the transport properties is expected from both the spin channels. Also around the E_F different states are contributing to the TDOS of both the channels so the relaxation time (τ) is also expected to be different for the both channels.

The value of magnetic moment of the compound comes out to be $\sim 5\ \mu_B$ which is as per the Slater-Pauling rule[26, 17] and is closer to the experimental values [10, 9]. The contribution from the Fe_1, Fe_2 and Co atoms is $\sim$ 1.41, 2.69 and 1.05 μ_B, respectively. The maximum contribution to the total magnetic moment is from the Fe_2 atom because of large exchange splitting in the $3d$ orbitals of Fe_2 atom.

The DOS plots of the compound show the contribution from different states around the E_F, so the transport behavior is also expected to be different for both the channels. Therefore we have studied the transport coefficients of the compound for both the spin channels and transport coefficients versus temperature plots are presented in Fig. 4. The Seebeck coefficient for spin-up and spin-dn channels are shown in Fig. 4(a) and 4(b), respectively. The S for spin-up channel is negative and its absolute value increases linearly with temperature. The room temperature value of $S_\uparrow$ is $\sim$ -11 μVK^{-1}. The negative value of S indicates that this is n-type thermoelectric material. For the spin-dn channel the variation of S with temperature is not linear, its absolute value firstly increases upto 300 K and then start decreasing upto 500 K. After 500 K the S becomes positive and again starts increasing with the temperature. The value of $S_\downarrow$ at room temperature is around -13 μVK^{-1}. Experimentally, the absolute value of S shows non linear increment with the temperature, which can only be understood if one combines the contributions from both the channels.

Also we have plotted the electrical conductivity with temperature for both the spin channels in Fig. 4(c and d). For the spin-up channel the σ/τ decreases with increasing temperature which corresponds to the metallic behavior. The value of σ at 300 K is about 38,000 $\Omega^{-1}cm^{-1}$. In the spin-dn channel it increases with the temperature like semiconductors. The spin-dn channel gives very less conductivity, clearly because of low value of DOS at the E_F. Both these channels show non linear variation with the temperature and have curvatures in opposite directions. However, in experimental plots the σ decreases almost linearly with the temperature, thus one can expect the overall combination from both the channels can give such temperature dependent behavior of σ.

Fig. 4(e and f) show the plots of electronic thermal conductivity with the temperature for both the spin channels. The κ_e/τ increases linearly with the temperature in the spin-up channel and at 300 K it is $\sim$ 28 $Wm^{-1}K^{-1}$. The spin-dn channel shows that κ_e/τ increases non-linearly with the temperature as there is a curvature. In the spin-dn channel κ_e is almost 10 times smaller and its value at the room temperature is $\sim$ 1 $Wm^{-1}K^{-1}$.

From the above discussions it is clear that the overall temperature dependent behavior of transport coefficients can be understood by combining the contributions from both the channels. Therefore we have applied the two current model to find the

total Seebeck coefficient, electrical conductivity and electronic thermal conductivity of the system. The total S, σ and κ_e are presented in the Fig. 5(a-c). The value of total S is negative and decreases with the temperature. The variation of S with temperature using the two current model shows non linear temperature dependence, as is observed experimentally. The absolute value of S at room temperature is ~ 11 μVK^{-1} and is closer to the experimental value of ~ 13 μVK^{-1}. The σ shows non linear increment with the temperature while κ_e increases linearly. The temperature dependent behavior of the σ and κ_e does not show agreement with the experimental data. This may be due to the reason that the value of the relaxation time has been taken same for the both spins. As mentioned earlier, the different states are contributing around the E_F therefore one expects different values of τ for both the spin channels.

If we take the values of τ equal to 5×10^{-15} and 2×10^{-15} s for spin-up and spin-dn channels, respectively the calculated values of σ and κ_e are found to be in fairly good agreement with the experimental data as evident from Fig. 6. The room temperature value of σ agrees with the experimental value of 19,000 $\Omega^{-1}cm^{-1}$. The plot of the κ_e versus temperature is found to increase almost linearly with the temperature. The value of κ_e at the room temperature is $\sim$14 $Wm^{-1}K^{-1}$ which is comparable with the experimental value. At this stage it is important to note that the experimental κ_e has been calculated by using the Wiedemann-Franz law and it shows a curvature at the higher temperature. However, calculated κ_e shows almost linear dependence. This deviation suggests the inadequacy of the Wiedemann-Franz law in understanding the temperature dependent behavior of the κ_e. Above results clearly show the importance of two current model in understanding the temperature dependent behavior of the transport coefficients. It is also important to note that we have not considered the temperature dependent τ, thus the values of σ and κ_e are expected to be different at the higher temperature.

4. Conclusions

The electronic and transport properties of the Fe_2CoSi inverse Heusler alloy are studied by combining the electronic band structure calculations with the Boltzmann transport theory. The spin-unpolarized calculation shows a very large DOS at the E_F and is unable to predict the correct temperature dependent behavior of the transport coefficients. The spin-polarized calculation provides ~ 25 times less DOS at the E_F for the spin-up channel whereas there is almost zero DOS in the spin-dn channel. Fe atom at 4c Wyckoff position shows large exchange splitting and contribute largely to the total magnetic moment. The $S^{\uparrow}$ varies linearly while $S^{\downarrow}$ shows non linear relation with the temperature. The $(\sigma/\tau)^{\uparrow}$ decreases while $(\sigma/\tau)^{\downarrow}$ increases non linearly with the temperature. The electronic thermal conductivity also found to increase with the increasing temperature for both the channels. The experimentally observed temperature dependent behavior of the compound is well explained by combining the transport coefficients of both the channels and considering different values of relaxation time. The room temperature values of S, σ

and κ_e are 11 μVK^{-1}, 19,000 $\Omega^{-1}cm^{-1}$ and 14 $Wm^{-1}K^{-1}$, respectively and show good agreement with the experimental values.

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5. Figures

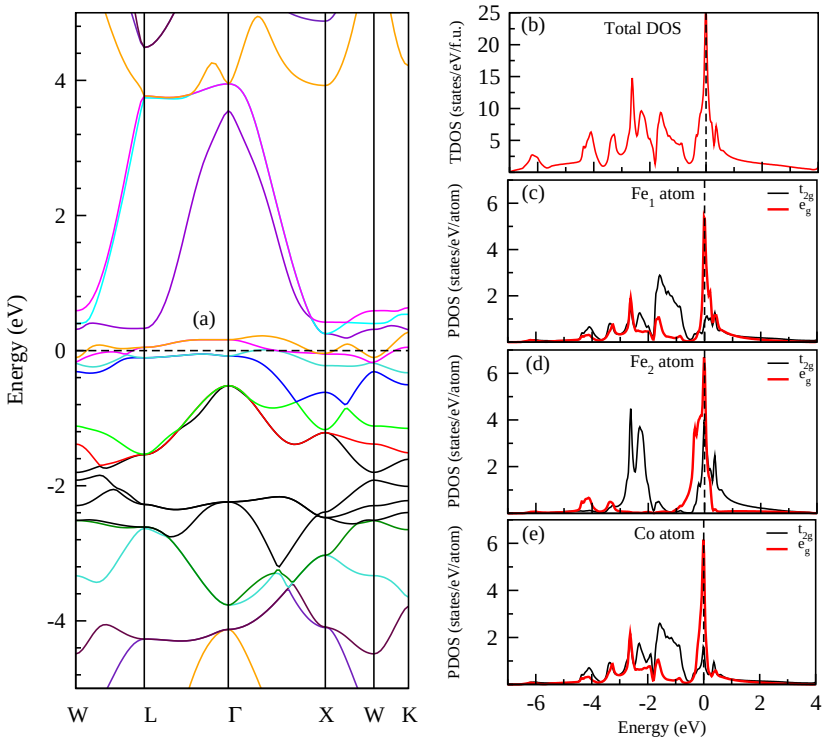

Figure 1. (Color online) (a) Electronic band structure, (b) TDOS, (c) PDOS of Fe_1 atom (Fe at 4a wyckoff position), (d) PDOS of Fe_2 atom (Fe at 4c wyckoff position) and (e) PDOS of Co atom for Fe_2CoSi compound in spin-unpolarized calculation.

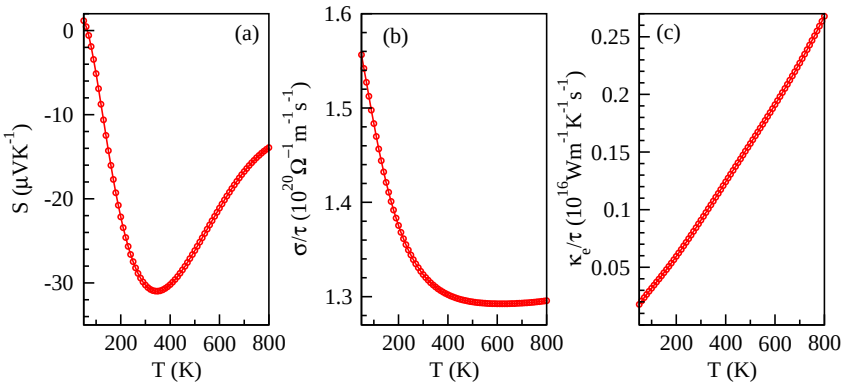

Figure 2. (Color online) Temperature variation of (a) Seebeck coefficient, (b) electrical conductivity and (c) electronic thermal conductivity with temperature for Fe_2CoSi compound in spin-unpolarized calculation.

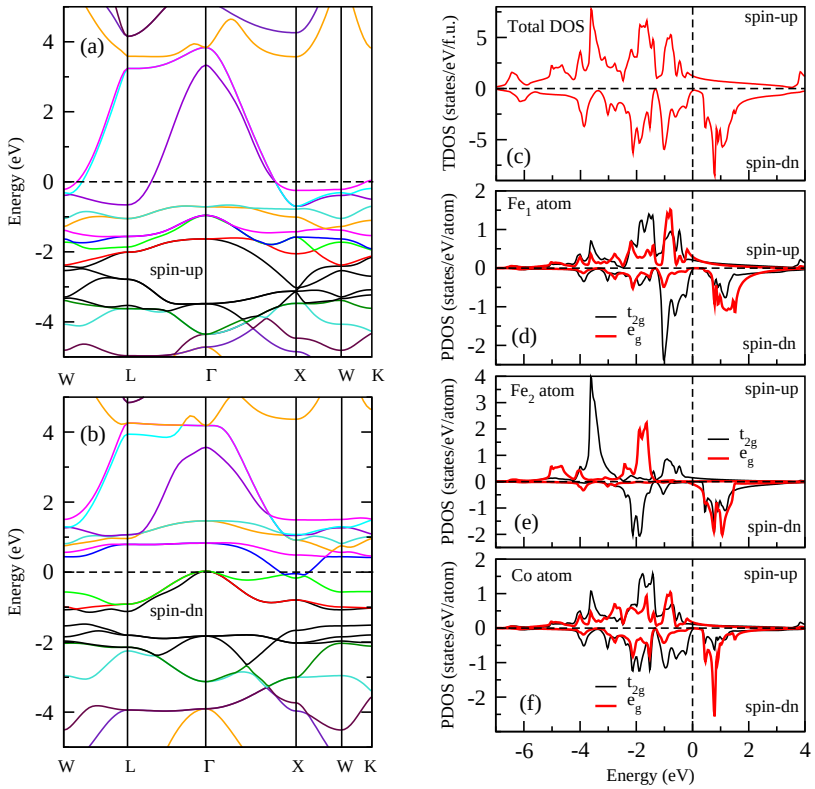

Figure 3. (Color online) Spin-polarized electronic band structures and Total and partial density of states plots of Fe_2CoSi. Shown are (a) band structure of spin-up channel, (b) band structure of spin-down channel, (c) TDOS, (d) PDOS of Fe_1 atom (Fe at 4*a* wyckoff position), (e) PDOS of Fe_2 atom (Fe at 4*c* wyckoff position) and (f) PDOS of Co atom.

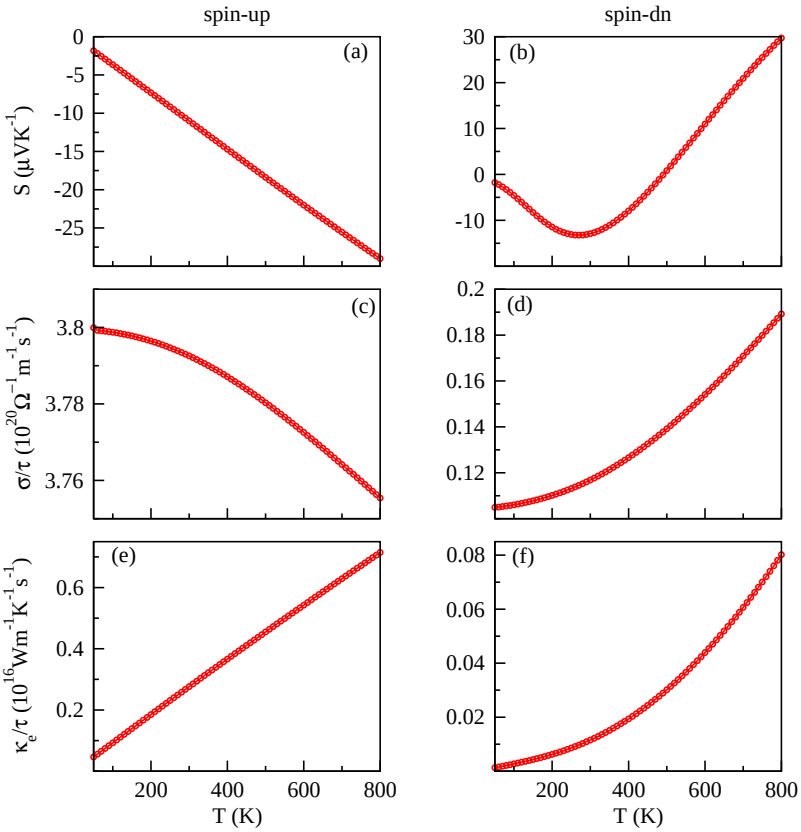

Figure 4. (Color online) Variation of transport coefficients with temperature. (a and b) Seebeck coefficient with temperature, (c and d) electrical conductivity with temperature and (e and f) electronic thermal conductivity with temperature.

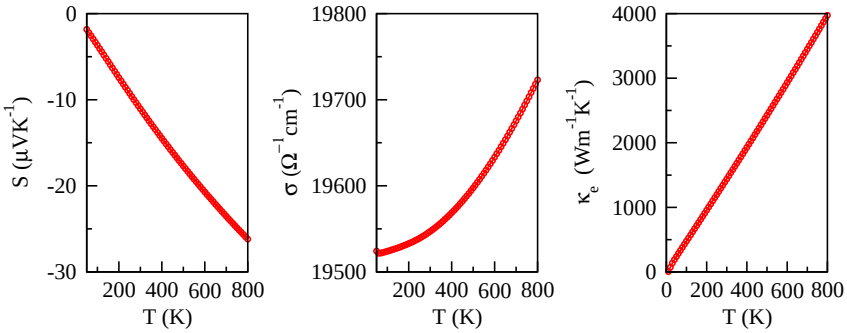

Figure 5. (Color online) Variation of (a) Seeebeck coefficient, (b) electrical conductivity and (c) electronic thermal conductivity with temperature within the two current model (relaxation time (τ) is taken to be 5×10^{-15} s for both the spin channels).

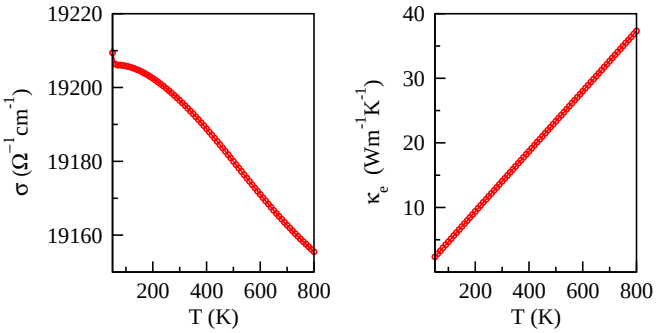

Figure 6. (Color online) Variation of (a) electrical conductivity and (b) electronic thermal conductivity with temperature within the two current model (τ is taken to be 2 $\times 10^{-15}$ and 5 $\times 10^{-15}$ s for spin-up and spin-dn channels, respectively).